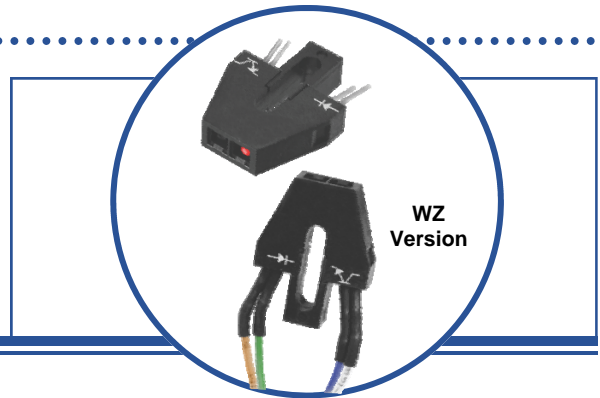


Reflective Object Sensor
OPB703, OPB704, OPB705
OPB703WZ, OPB704WZ, OPB705WZ, OPB70AWZ,
OPB70BWZ, OPB70CWZ, OPB70DWZ



Features:

- Phototransistor output
- High sensitivity
- Low-cost plastic housing
- Available with lenses for dust protection and ambient light filtration



Description:

The **OPB703, OPB704** and **OPB705** consist of an Infrared (890nm) Light Emitting Diode (LED) and a NPN silicon Phototransistor, mounted side-by-side on converging optical axes in a black plastic housing and are designed for PCBoard mounting. The **OPB703WZ, OPB704WZ, OPB705WZ** and **OPB70BWZ** are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

The **OPB70AWZ** consist of an Infrared (890nm) Light Emitting Diode (LED) and a NPN silicon Photodarlington, mounted side-by-side on converging optical axes in a black plastic housing and are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

The **OPB70CWZ** and **OPB70DWZ** consist of an Visible (Red 640nm) Light Emitting Diode (LED) and a NPN silicon Phototransistor or Rbe Phototransistor, mounted side-by-side on converging optical axes in a black plastic housing and are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

Various lens options are available: No lens for the (**OPB703, OPB703WZ**), blue window for dust protection for the (**OPB704, OPB704WZ, OPB70BWZ**) and Aperture lens for improved resolution for the (**OPB705, OPB705WZ, OPB70AWZ, OPB70CWZ** and **OPB70DWZ**).

The phototransistor responds to illumination from the emitter when a reflective object passes within the field of view centered typically at 0.15" (3.8 mm).

Custom electrical, wire, cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

Ordering Information						
Part	LED Peak			Lead or Wire		
OPB703	890 nm	Transistor	None	0.160" Leads		
OPB703WZ				24" / 26 AWG Wire		
OPB704			Blue Window	0.160" Leads		
OPB704WZ				24" / 26 AWG Wire		
OPB705			Aperture	0.160" Leads		
OPB705WZ				24" / 26 AWG Wire		
OPB70AWZ					Darlington	
OPB70BWZ					Rbe Transistor	
OPB70CWZ			640 nm		Rbe Transistor	Aperture
OPB70DWZ				Transistor		



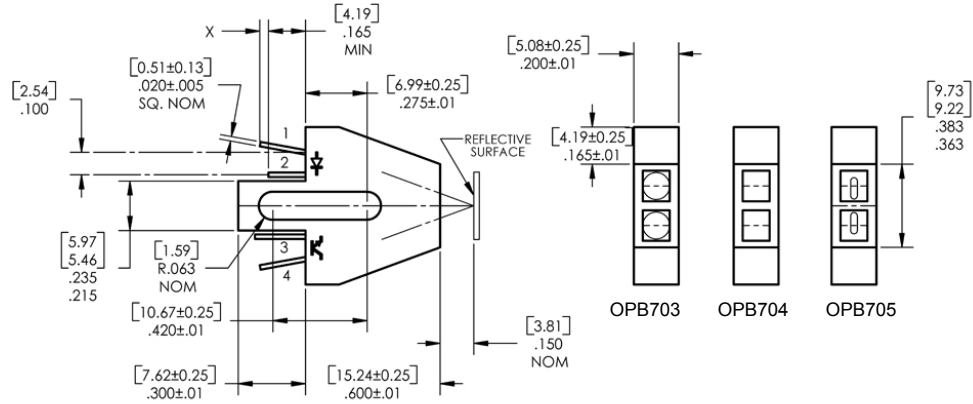
RoHS

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

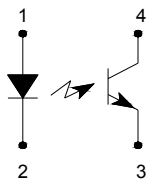
Reflective Object Sensor
OPB703, OPB704, OPB705
OPB703WZ, OPB704WZ, OPB705WZ, OPB70AWZ,
OPB70BWZ, OPB70CWZ, OPB70DWZ



OPB 703, OPB704, OPB705



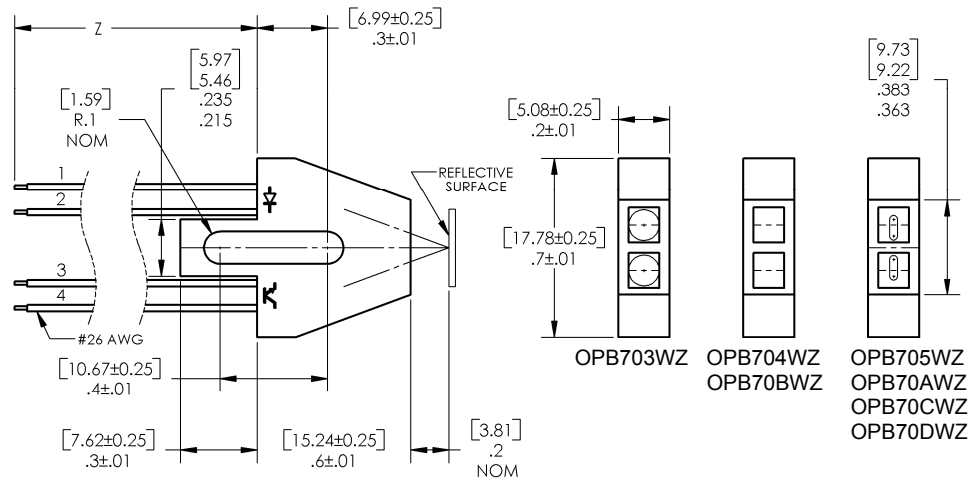
OPB703, OPB704, OPB705



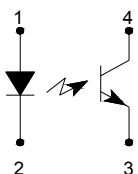
Pin #	Description	Pin #	Description
1	Anode	4	Collector
2	Cathode	3	Emitter

OPB 703WZ, OPB704WZ, OPB705WZ, OPB70AWZ, OPB70BWZ, OPB70CWZ, OPB70DWZ

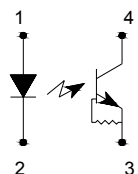
Pin - Color	LED
1 – Orange	Anode
2 – Green	Cathode
3 – Blue	Emitter
4 – White	Collector



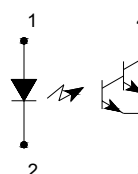
OPB703WZ, OPB704WZ, OPB705WZ, OPB70DWZ



OPB703BZ, OPB704CZ



OPB703AWZ



DIMENSIONS ARE IN: [MILLIMETERS]
INCHES

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

Reflective Object Sensor
OPB703, OPB704, OPB705
OPB703WZ, OPB704WZ, OPB705WZ, OPB70AWZ,
OPB70BWZ, OPB70CWZ, OPB70DWZ



Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Storage Temperature Range	-40°C to +85° C
Lead Soldering Temperature [1/16 inch (1.6 mm) from the case for 5 sec. with soldering iron]	240° C ⁽¹⁾

Input Diode

Forward DC Current	40 mA
Reverse DC Voltage	2 V
Power Dissipation	100 mW ⁽²⁾

Output Phototransistor

Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Collector DC Current	25 mA
Power Dissipation	100 mW ⁽²⁾

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

(OPB703, OPB703WZ, OPB704, OPB704WZ, OPB705, OPB705WZ, OPB70BWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
--------	-----------	-----	-----	-----	-------	-----------------

Input Diode (See OP265 for additional information — for reference only)

V_F	Forward Voltage	0.9	-	1.7	V	$I_F = 40\text{mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2\text{V}$

Output Phototransistor (See OP505 for additional information — for reference only)

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{CE} = 100\ \mu\text{A}$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	-	-	V	$I_{EC} = 100\ \mu\text{A}$
I_{CEO}	Collector Dark Current	-	-	250	nA	$V_{CE} = 10\text{V}, I_F = 0, E_E = 0$

Coupled

$I_{C(ON)}$	On-State Collector Current					
	OPB703, OPB703WZ	0.30	-	2.5	mA	$V_{CE} = 5\text{V}, I_F = 40\text{mA}, d = 0.15''^{(3)(7)}$
	OPB704, OPB704WZ	0.20	-	2.5		
OPB705, OPB705WZ, OPB70BWZ	0.15	-	1.0			
I_{CX}	Crosstalk				μA	$V_{CE} = 5\text{V}, I_F = 40\text{mA}^{(6)}$
	OPB703, OPB703WZ	-	-	20		
	OPB704, OPB704WZ	-	-	20		
	OPB705, OPB705WZ, OPB90BWZ	-	-	10		

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) For OPB703, OPB704 and OPB705, derate linearly 1.67 mW/° C above 25° C.
- (3) For OPB703WZ, OPB704WZ, OPB705WZ and OPB70BWZ, derate linearly 1.82 mW/° C above 25° C.
- (4) The distance from the assembly face to the reflective surface is d.
- (5) Lower curve is based on a calculated worst-case condition, rather than the conventional -2 Ω limit.
- (6) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (7) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.
- (8) All parameters tested using pulse techniques.

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

Reflective Object Sensor
OPB703, OPB704, OPB705
OPB703WZ, OPB704WZ, OPB705WZ, OPB70AWZ,
OPB70BWZ, OPB70CWZ, OPB70DWZ



Electrical Characteristics ($T_A = 25^\circ \text{C}$ unless otherwise noted)
(OPB70AWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
--------	-----------	-----	-----	-----	-------	-----------------

Input Diode (See OP265 for additional information — for reference only)

V_F	Forward Voltage	0.9	-	1.7	V	$I_F = 40\text{mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2 \text{ V}$

Output PhotoDarlington (See OP535 for additional information — for reference only)

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	15	-	-	V	$I_{CE} = 1.0 \text{ mA}, E_E = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	-	-	V	$I_{EC} = 100\mu\text{A}, E_E = 0$
I_{CEO}	Collector Dark Current	-	-	250	nA	$V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0$

Coupled

$I_{C(ON)}$	On-State Collector Current	5.0	-	26.0	mA	$V_{CE} = 5 \text{ V}, I_F = 40\text{mA}, d = 0.15''^{(2)(6)}$
$V_{(SAT)}$	Saturation Voltage	0.60	-	1.15	V	$I_{C(ON)} = 400 \mu\text{A}, I_F = 40\text{mA}, d = 0.15''^{(2)(6)}$
I_{CX}	Crosstalk	-	-	25	μA	$V_{CE} = 5 \text{ V}, I_F = 40\text{mA}^{(5)}$

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly $1.82 \text{ mW}/^\circ \text{C}$ above 25°C .
- (3) The distance from the assembly face to the reflective surface is d .
- (4) Lower curve is based on a calculated worst-case condition, rather than the conventional -2Ω limit.
- (5) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (6) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.
- (7) All parameters tested using pulse techniques.

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

Reflective Object Sensor
OPB703, OPB704, OPB705
OPB703WZ, OPB704WZ, OPB705WZ, OPB70AWZ,
OPB70BWZ, OPB70CWZ, OPB70DWZ



Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)
(OPB70CWZ and OPB70DWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
--------	-----------	-----	-----	-----	-------	-----------------

Input Diode (See OVLAS6CB8 for additional information — for reference only)

V_F	Forward Voltage	1.6	-	2.5	V	$I_F = 40\text{mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2\text{V}$

Output Phototransistor (See OP505 for additional information — for reference only)

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{CE} = 100\ \mu\text{A}, I_F = 0, E_E = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	0.4	-	-	V	$I_{EC} = 100\ \mu\text{A}, I_F = 0, E_E = 0$
I_{CEO}	Collector Dark Current	-	-	250	nA	$V_{CE} = 10\text{V}, I_F = 0, E_E = 0$

Coupled

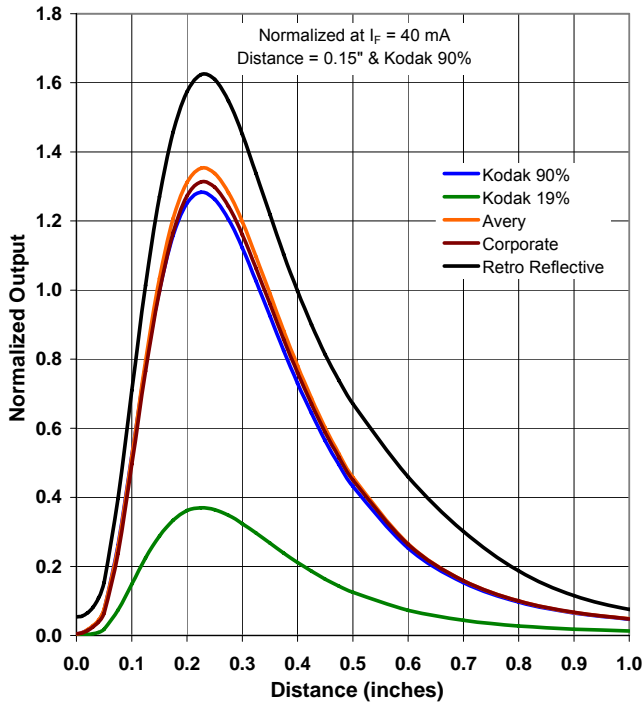
$I_{C(ON)}$	On-State Collector Current OPB70CWZ, OPB70DWZ	0.10	-	1.0	mA	$V_{CE} = 5\text{V}, I_F = 40\text{mA}, d = 0.15''^{(2)(6)}$
$V_{(SAT)}$	Saturation Voltage	-	-	0.4	V	$I_{C(ON)} = 400\ \mu\text{A}, I_F = 40\text{mA}, d = 0.15''^{(2)(6)}$
I_{CX}	Crosstalk OPB70CWZ, OPB70DWZ	-	-	0.1	μA	$V_{CE} = 5\text{V}, I_F = 40\text{mA}^{(5)}$

Notes:

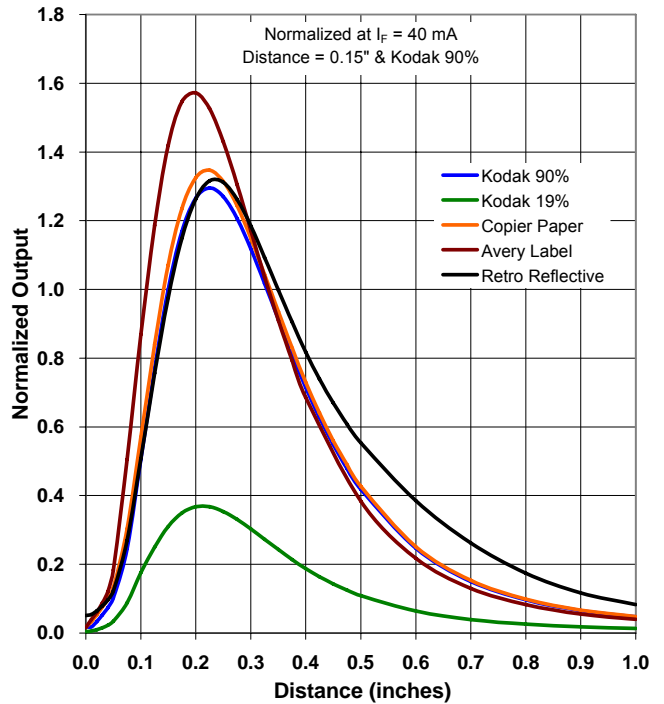
- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) For OPB703WZ, OPB704WZ, OPB705WZ and OPB70BWZ, derate linearly $1.82\text{ mW}/^\circ\text{C}$ above 25°C .
- (3) The distance from the assembly face to the reflective surface is d .
- (4) Lower curve is based on a calculated worst-case condition, rather than the conventional -2Ω limit.
- (5) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (6) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.
- (7) All parameters tested using pulse techniques.

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

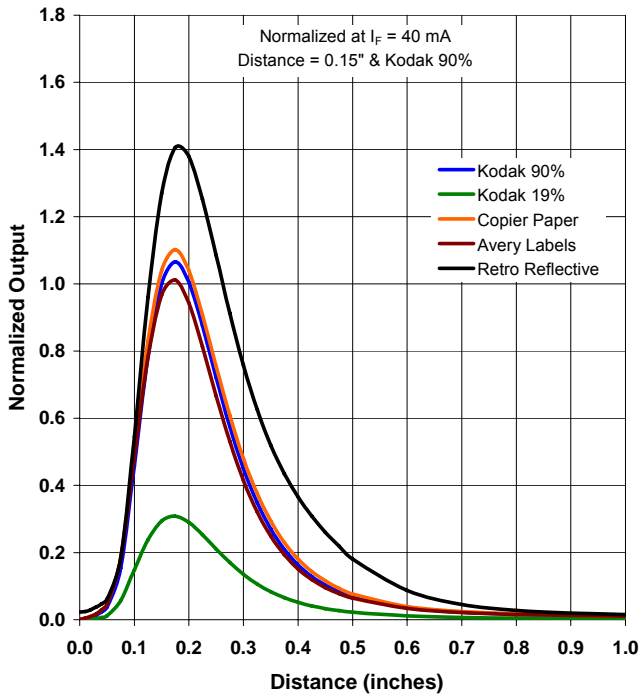
OPB703—Output Distance



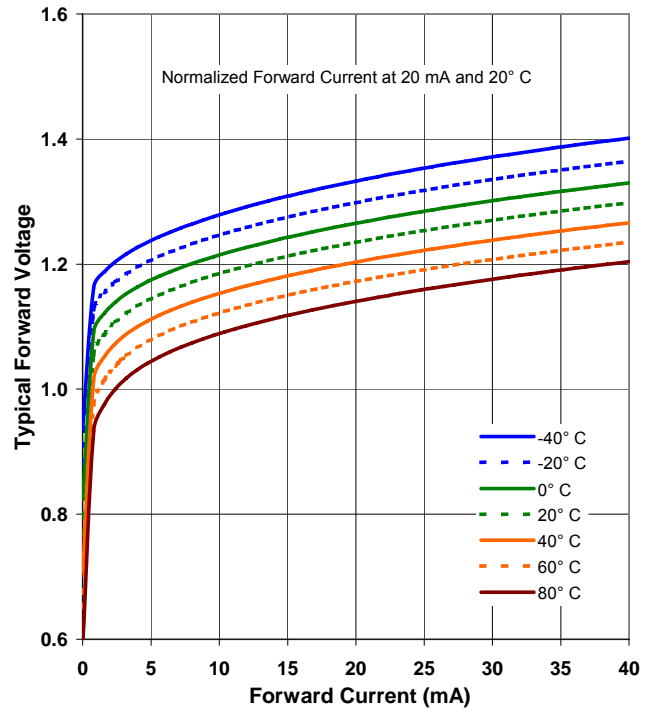
OPB704, OPB70B—Output Distance



OPB705, OPB70A, OPB70C, OPB70D—Output Distance



Forward Voltage vs Forward Current vs Temp



OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.